

# COMPLEMENTARY SILICON POWER TRANSISTORS

- STMicroelectronics PREFERRED SALESTYPES
- COMPLEMENTARY PNP NPN DEVICES
- MEDIUM VOLTAGE CAPABILITY
- SURFACE-MOUNTING TO-252 (DPAK) POWER PACKAGE IN TAPE & REEL (SUFFIX "T4")
- ELECTRICAL SIMILAR TO MJE340 AND MJE350

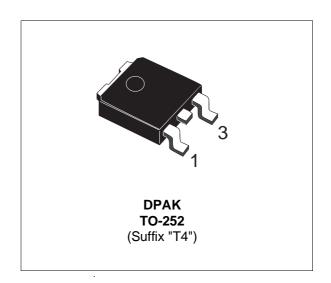
#### **APPLICATIONS**

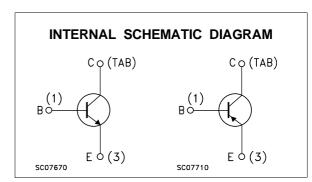
- SOLENOID/RELAY DRIVERS
- GENERAL PURPOSE SWITCHING AND AMPLIFIER

#### **DESCRIPTION**

The MJD340 and MJD350 form complementary NPN - PNP pairs.

They are manufactured using Medium Voltage Epitaxial-Planar technology, resulting in a rugged high performance cost-effective transistor.





#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit	
		NPN	MJD340	
		PNP	MJD350	
V <sub>CBO</sub>	Collector-Base Voltage (IE = 0)		300	V
V <sub>CEO</sub>	Collector-Emitter Voltage (I <sub>B</sub> = 0)		300	V
V <sub>EBO</sub>	Emitter-Base Voltage (IC = 0)		3	V
Ic	Collector Current		0.5	А
I <sub>CM</sub>	Collector Peak Current (tp = 25 °C)		0.75	А
P <sub>tot</sub>	Total Power Dissipation at T <sub>case</sub> ≤ 25 °C	15	W	
T <sub>stg</sub>	Storage Temperature		-65 to 150	°C
Tj	Max Operating Junction Temperature		150	°C

For PNP types voltage and current values are negative.

September 2003 1/5

### THERMAL DATA

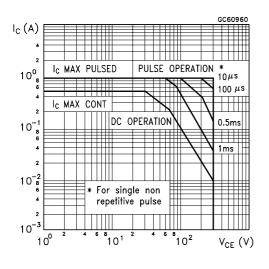
R <sub>thj-case</sub>	Thermal Resistance Junction-case	Max	8.33	°C/W	
$R_{thj-amb}$	Thermal Resistance Junction-ambient	Max	100	°C/W	

# **ELECTRICAL CHARACTERISTICS** (T<sub>case</sub> = 25 °C unless otherwise specified)

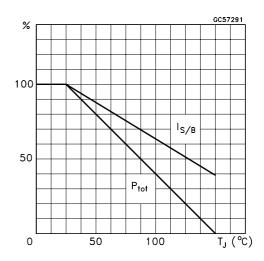
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector Cut-off Current (v <sub>BE</sub> = 0)	V <sub>CB</sub> = 300 V			0.1	mA
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 3 V			0.1	mA
V <sub>CEO(sus)</sub> *	Collector-Emitter Sustaining Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 1 mA	300			V
h <sub>FE</sub> *	DC Current Gain	$I_C = 50 \text{ mA}$ $V_{CE} = 10 \text{ V}$	30		240	

<sup>\*</sup> Pulsed: Pulse duration =  $300 \,\mu s$ , duty cycle  $\leq 2 \,\%$ For PNP type voltage and current values are negative.

## Safe Operating Area

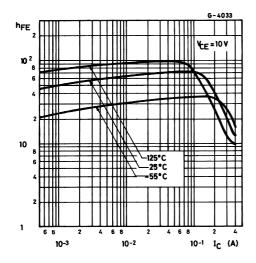


## **Derating Curve**

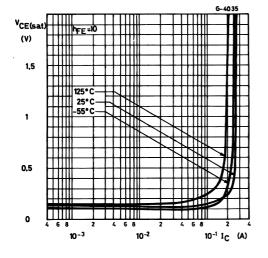


2/5

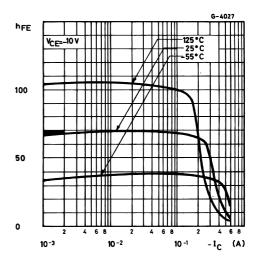
# DC Current Gain (NPN type)



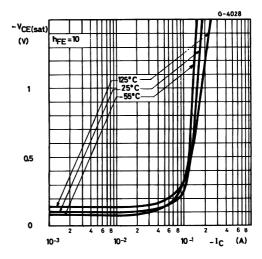
# Collector Emitter Saturation Voltage (NPN type)



# DC Current Gain (PNP type)

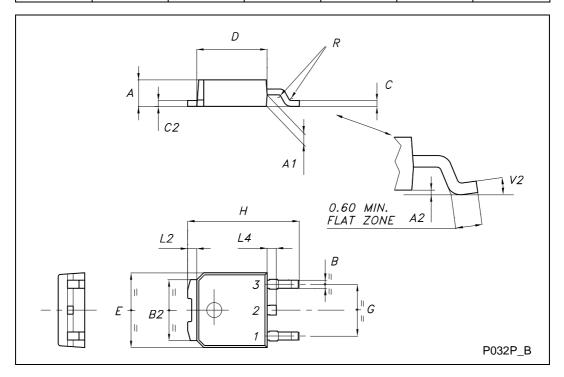


Collector Emitter Saturation Voltage (PNP type)



TO-252	(DPAK)	<b>MECHANICAL</b>	DATA
I O-ZJZ	IDI AIN	MILCHAINCAL	$\nu$ $\alpha$ $\iota$ $\alpha$

DIM.	mm			inch			
J.W.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А	2.20		2.40	0.087		0.094	
A1	0.90		1.10	0.035		0.043	
A2	0.03		0.23	0.001		0.009	
В	0.64		0.90	0.025		0.035	
B2	5.20		5.40	0.204		0.213	
С	0.45		0.60	0.018		0.024	
C2	0.48		0.60	0.019		0.024	
D	6.00		6.20	0.236		0.244	
E	6.40		6.60	0.252		0.260	
G	4.40		4.60	0.173		0.181	
Н	9.35		10.10	0.368		0.398	
L2		0.8			0.031		
L4	0.60		1.00	0.024		0.039	
V2	0°		8°	0°		0°	



4/5

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specification mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2003 STMicroelectronics – All Rights reserved STMicroelectronics GROUP OF COMPANIES

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States.

http://www.st.com

